

DATA SHEET

74HC3G14; 74HCT3G14 **Inverting Schmitt-triggers**

Product specification
Supersedes data of 2002 Jul 23

2003 Nov 04

Inverting Schmitt-triggers

74HC3G14; 74HCT3G14

FEATURES

- Wide supply voltage range from 2.0 to 6.0 V
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- Unlimited input rise and fall times
- Very small 8 pins package
- ESD protection:
HBM EIA/JESD22-A114-A exceeds 2000 V
MM EIA/JESD22-A115-A exceeds 200 V.
- Specified from -40 to $+85$ °C and -40 to $+125$ °C.

APPLICATIONS

- Wave and pulse shapers for highly noisy environments
- Astable multivibrators
- Monostable multivibrators
- Output capability: standard.

DESCRIPTION

The 74HC3G/HCT3G14 is a high-speed Si-gate CMOS device.

The 74HC3G/HCT3G14 provides three inverting buffers with Schmitt-trigger action. This device is capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25$ °C; $t_r = t_f \leq 6.0$ ns.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC3G14	HCT3G14	
t_{PHL}/t_{PLH}	propagation delay nA to nY	$C_L = 50$ pF; $V_{CC} = 4.5$ V	16	21	ns
C_I	input capacitance		2	2	pF
C_{PD}	power dissipation capacitance per buffer	notes 1 and 2	10	10	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

N = total switching outputs;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

2. For HC3G14 the condition is $V_I = \text{GND to } V_{CC}$.

For HCT3G14 the condition is $V_I = \text{GND to } V_{CC} - 1.5$ V.

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FUNCTION TABLE

See note 1.

INPUT	OUTPUT
nA	nY
L	H
H	L

Note

1. H = HIGH voltage level;
L = LOW voltage level.

ORDERING INFORMATION

TYPE NUMBER	PACKAGE					
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE	MARKING
74HC3G14DP	-40 to +125 °C	8	TSSOP8	plastic	SOT505-1	H14
74HCT3G14DP	-40 to +125 °C	8	TSSOP8	plastic	SOT505-1	T14
74HC3G14DC	-40 to +125 °C	8	VSSOP8	plastic	SOT765-1	H14
74HCT3G14DC	-40 to +125 °C	8	VSSOP8	plastic	SOT765-1	T14

PINNING

PIN	SYMBOL	DESCRIPTION
1	1A	data input 1A
2	3Y	data output 3Y
3	2A	data input 2A
4	GND	ground (0 V)
5	2Y	data output 2Y
6	3A	data input 3A
7	1Y	data output 1Y
8	V _{CC}	supply voltage

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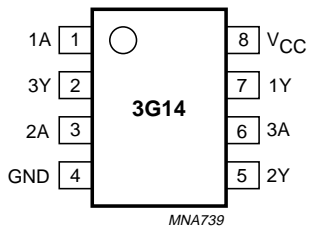


Fig.1 Pin configuration.

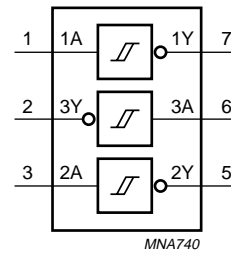


Fig.2 Logic symbol.

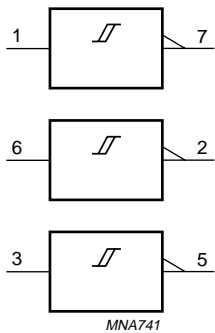


Fig.3 IEC logic symbol.

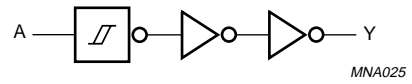


Fig.4 Logic diagram (one driver).

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	74HC3G14			74HCT3G14			UNIT
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
V_{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
V_I	input voltage		0	–	V_{CC}	0	–	V_{CC}	V
V_O	output voltage		0	–	V_{CC}	0	–	V_{CC}	V
T_{amb}	operating ambient temperature	see DC and AC characteristics per device	–40	+25	+125	–40	+25	+125	°C

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	supply voltage		–0.5	+7.0	V
I_{IK}	input diode current	$V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$; note 1	–	±20	mA
I_{OK}	output diode current	$V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$; note 1	–	±20	mA
I_O	output source or sink current	$-0.5\text{ V} < V_O < V_{CC} + 0.5\text{ V}$; note 1	–	25	mA
I_{CC}	V_{CC} or GND current	note 1	–	50	mA
T_{stg}	storage temperature		–65	+150	°C
P_D	power dissipation	$T_{amb} = -40$ to $+125\text{ °C}$; note 2	–	300	mW

Notes

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. Above 110 °C the value of P_D derates linearly with 8 mW/K.

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DC CHARACTERISTICS

Type 74HC3G14

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V _{CC} (V)				
T_{amb} = 25 °C							
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}					
		I _O = -20 μA	2.0	1.9	2.0	–	V
		I _O = -20 μA	4.5	4.4	4.5	–	V
		I _O = -20 μA	6.0	5.9	6.0	–	V
		I _O = -4.0 mA	4.5	4.18	4.32	–	V
		I _O = -5.2 mA	6.0	5.68	5.81	–	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}					
		I _O = 20 μA	2.0	–	0	0.1	V
		I _O = 20 μA	4.5	–	0	0.1	V
		I _O = 20 μA	6.0	–	0	0.1	V
		I _O = 4.0 mA	4.5	–	0.15	0.26	V
		I _O = 5.2 mA	6.0	–	0.16	0.26	V
I _{LI}	input leakage current	V _I = V _{CC} or GND	6.0	–	–	±0.1	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0	6.0	–	–	1.0	μA
T_{amb} = -40 to +85 °C							
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}					
		I _O = -20 μA	2.0	1.9	–	–	V
		I _O = -20 μA	4.5	4.4	–	–	V
		I _O = -20 μA	6.0	5.9	–	–	V
		I _O = -4.0 mA	4.5	4.13	–	–	V
		I _O = -5.2 mA	6.0	5.63	–	–	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}					
		I _O = 20 μA	2.0	–	–	0.1	V
		I _O = 20 μA	4.5	–	–	0.1	V
		I _O = 20 μA	6.0	–	–	0.1	V
		I _O = 4.0 mA	4.5	–	–	0.33	V
		I _O = 5.2 mA	6.0	–	–	0.33	V
I _{LI}	input leakage current	V _I = V _{CC} or GND	6.0	–	–	±1.0	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0	6.0	–	–	10	μA

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SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V _{CC} (V)				
T_{amb} = -40 to +125 °C							
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}					
		I _O = -20 μA	2.0	1.9	-	-	V
		I _O = -20 μA	4.5	4.4	-	-	V
		I _O = -20 μA	6.0	5.9	-	-	V
		I _O = -4.0 mA	4.5	3.7	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}					
		I _O = 20 μA	2.0	-	-	0.1	V
		I _O = 20 μA	4.5	-	-	0.1	V
		I _O = 20 μA	6.0	-	-	0.1	V
		I _O = 4.0 mA	4.5	-	-	0.4	V
I _{LI}	input leakage current	V _I = V _{CC} or GND	6.0	-	-	±1.0	μA
		I _O = 0	6.0	-	-	20	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0	6.0	-	-	20	μA

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Type 74HCT3G14

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V _{CC} (V)				
T_{amb} = 25 °C							
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}	4.5	4.4	4.5	–	V
		I _O = –20 μA	4.5	4.18	4.32	–	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}	4.5	–	0	0.1	V
		I _O = 20 μA	4.5	–	0.15	0.26	V
I _{LI}	input leakage current	V _I = V _{CC} or GND	5.5	–	–	±0.1	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0	5.5	–	–	1.0	μA
ΔI _{CC}	additional supply current per input	V _I = V _{CC} – 2.1 V; I _O = 0	4.5 to 5.5	–	–	300	μA
T_{amb} = –40 to +85 °C							
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}	4.5	4.4	–	–	V
		I _O = –20 μA	4.5	4.13	–	–	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}	4.5	–	–	0.1	V
		I _O = 20 μA	4.5	–	–	0.33	V
I _{LI}	input leakage current	V _I = V _{CC} or GND	5.5	–	–	±1.0	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0	5.5	–	–	10	μA
ΔI _{CC}	additional supply current per input	V _I = V _{CC} – 2.1 V; I _O = 0	4.5 to 5.5	–	–	375	μA
T_{amb} = –40 to +125 °C							
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}	4.5	4.4	–	–	V
		I _O = –20 μA	4.5	3.7	–	–	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}	4.5	–	–	0.1	V
		I _O = 20 μA	4.5	–	–	0.4	V
I _{LI}	input leakage current	V _I = V _{CC} or GND	5.5	–	–	±1.0	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0	5.5	–	–	20	μA
ΔI _{CC}	additional supply current per input	V _I = V _{CC} – 2.1 V; I _O = 0	4.5 to 5.5	–	–	410	μA

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TRANSFER CHARACTERISTICS

Type 74HC3G14

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	V _{CC} (V)				
T_{amb} = 25 °C							
V _{T+}	positive going threshold voltage	see Figs. 5 and 6	2.0	1.0	1.18	1.5	V
			4.5	2.3	2.6	3.15	V
			6.0	3.0	3.46	4.2	V
V _{T-}	negative going threshold voltage	see Figs. 5 and 6	2.0	0.3	0.6	0.9	V
			4.5	1.13	1.47	2.0	V
			6.0	1.5	2.06	2.6	V
V _H	hysteresis voltage (V _{T+} - V _{T-})	see Figs. 5 and 6	2.0	0.3	0.6	1.0	V
			4.5	0.6	1.13	1.4	V
			6.0	0.8	1.40	1.7	V
T_{amb} = -40 to +85 °C							
V _{T+}	positive going threshold voltage	see Figs. 5 and 6	2.0	1.0	–	1.5	V
			4.5	2.3	–	3.15	V
			6.0	3.0	–	4.2	V
V _{T-}	negative going threshold voltage	see Figs. 5 and 6	2.0	0.3	–	0.9	V
			4.5	1.13	–	2.0	V
			6.0	1.5	–	2.6	V
V _H	hysteresis voltage (V _{T+} - V _{T-})	see Figs. 5 and 6	2.0	0.3	–	1.0	V
			4.5	0.6	–	1.4	V
			6.0	0.8	–	1.7	V
T_{amb} = -40 to +125 °C							
V _{T+}	positive going threshold voltage	see Figs. 5 and 6	2.0	1.0	–	1.5	V
			4.5	2.3	–	3.15	V
			6.0	3.0	–	4.2	V
V _{T-}	negative going threshold voltage	see Figs. 5 and 6	2.0	0.3	–	0.9	V
			4.5	1.13	–	2.0	V
			6.0	1.5	–	2.6	V
V _H	hysteresis voltage (V _{T+} - V _{T-})	see Figs. 5 and 6	2.0	0.3	–	1.0	V
			4.5	0.6	–	1.4	V
			6.0	0.8	–	1.7	V

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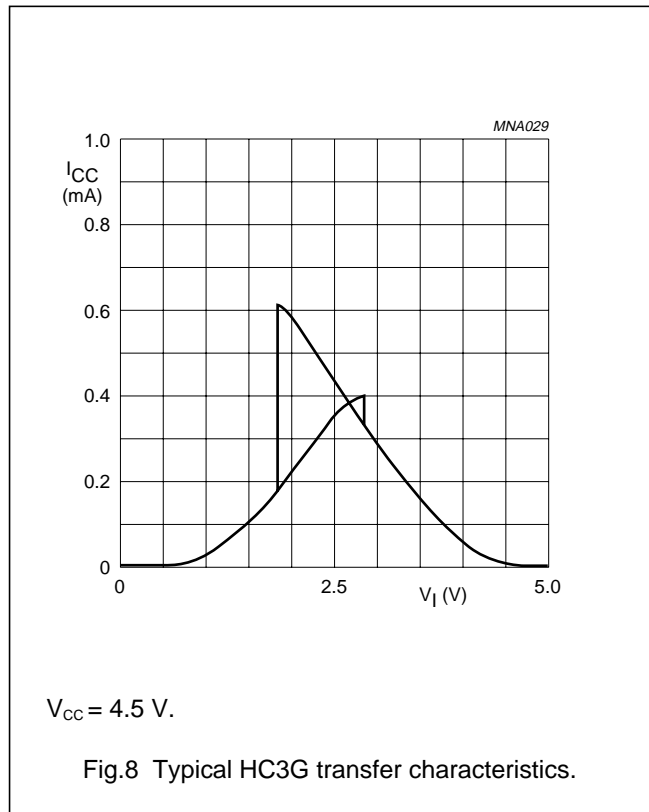
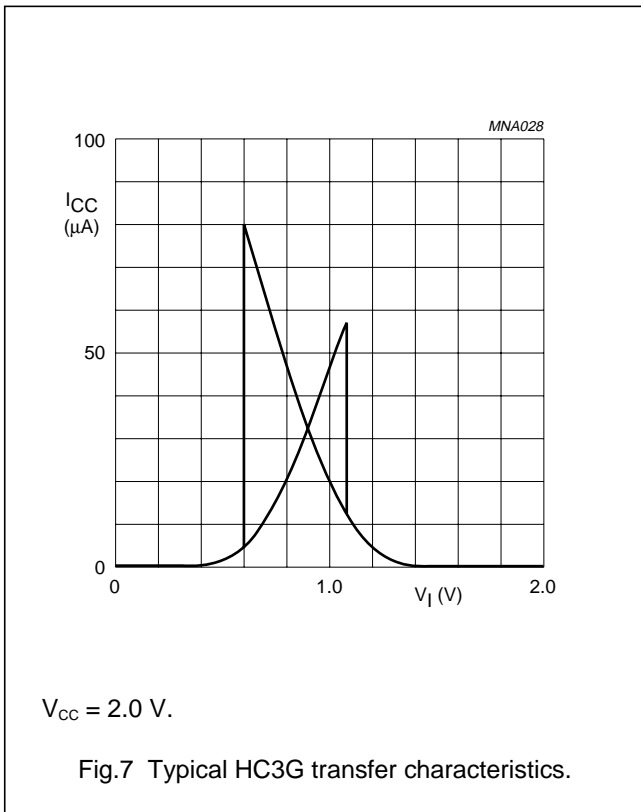
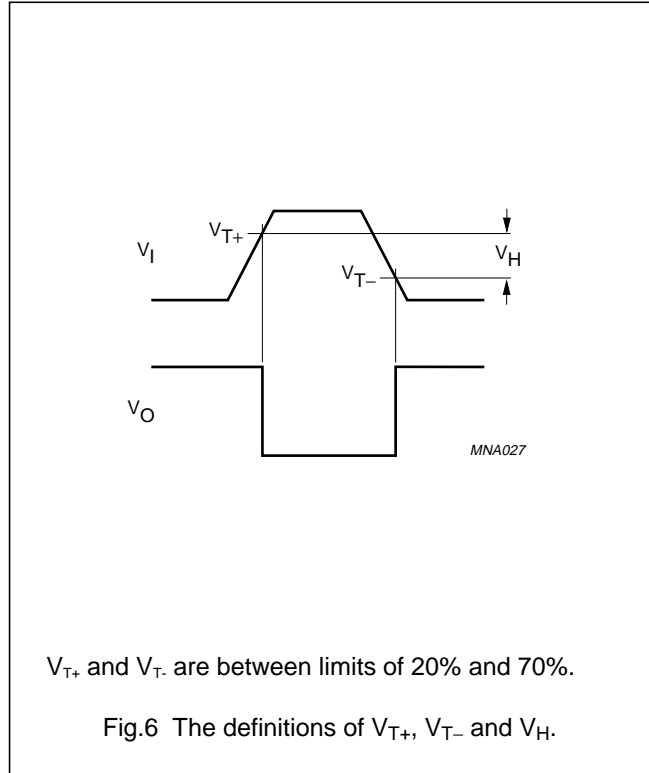
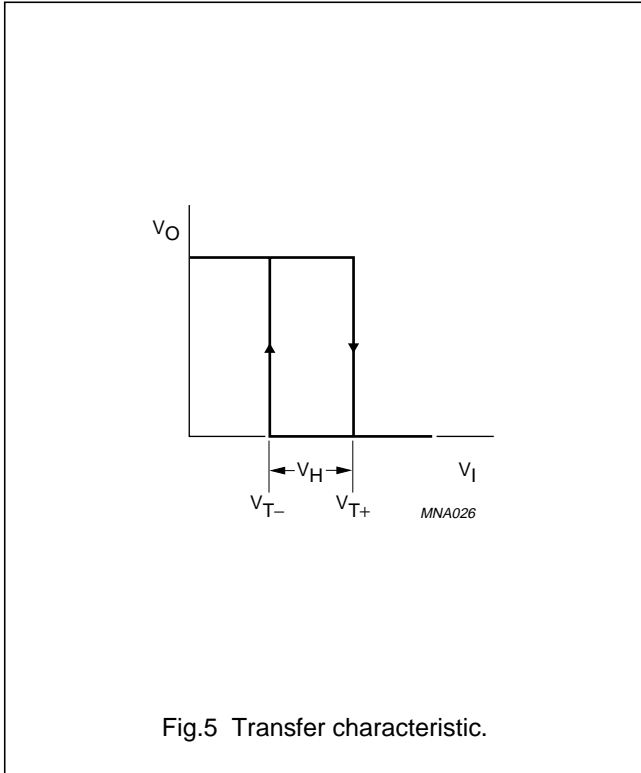
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V _{CC} (V)				
T_{amb} = 25 °C							
V _{T+}	positive going threshold voltage	see Figs. 5 and 6	4.5	1.2	1.58	1.9	V
			5.5	1.4	1.78	2.1	V
V _{T-}	negative going threshold voltage	see Figs. 5 and 6	4.5	0.5	0.87	1.2	V
			5.5	0.6	1.11	1.4	V
V _H	hysteresis voltage (V _{T+} - V _{T-})	see Figs. 5 and 6	4.5	0.4	0.71	–	V
			5.5	0.4	0.67	–	V
T_{amb} = -40 to +85 °C							
V _{T+}	positive going threshold voltage	see Figs. 5 and 6	4.5	1.2	–	1.9	V
			5.5	1.4	–	2.1	V
V _{T-}	negative going threshold voltage	see Figs. 5 and 6	4.5	0.5	–	1.2	V
			5.5	0.6	–	1.4	V
V _H	hysteresis voltage (V _{T+} - V _{T-})	see Figs. 5 and 6	4.5	0.4	–	–	V
			5.5	0.4	–	–	V
T_{amb} = -40 to +125 °C							
V _{T+}	positive going threshold voltage	see Figs. 5 and 6	4.5	1.2	–	1.9	V
			5.5	1.4	–	2.1	V
V _{T-}	negative going threshold voltage	see Figs. 5 and 6	4.5	0.5	–	1.2	V
			5.5	0.6	–	1.4	V
V _H	hysteresis voltage (V _{T+} - V _{T-})	see Figs. 5 and 6	4.5	0.4	–	–	V
			5.5	0.4	–	–	V

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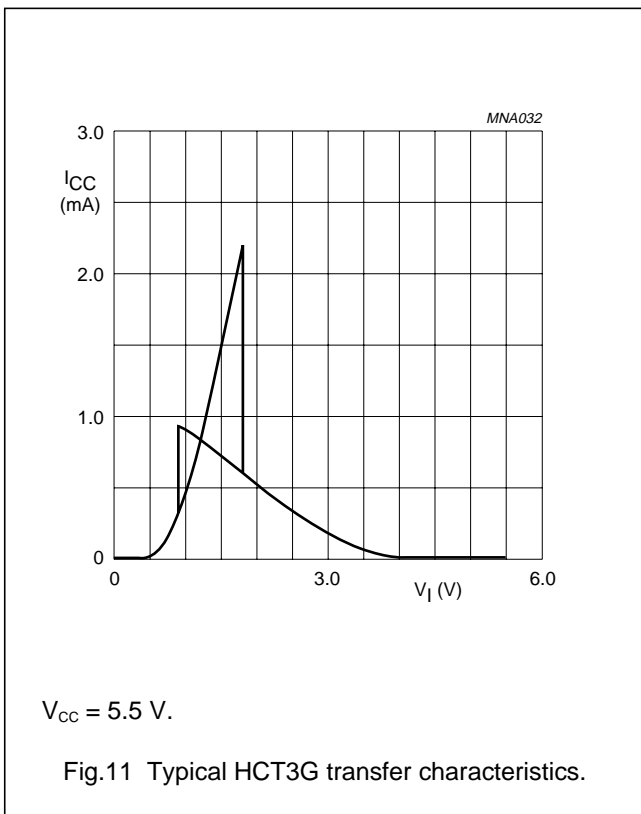
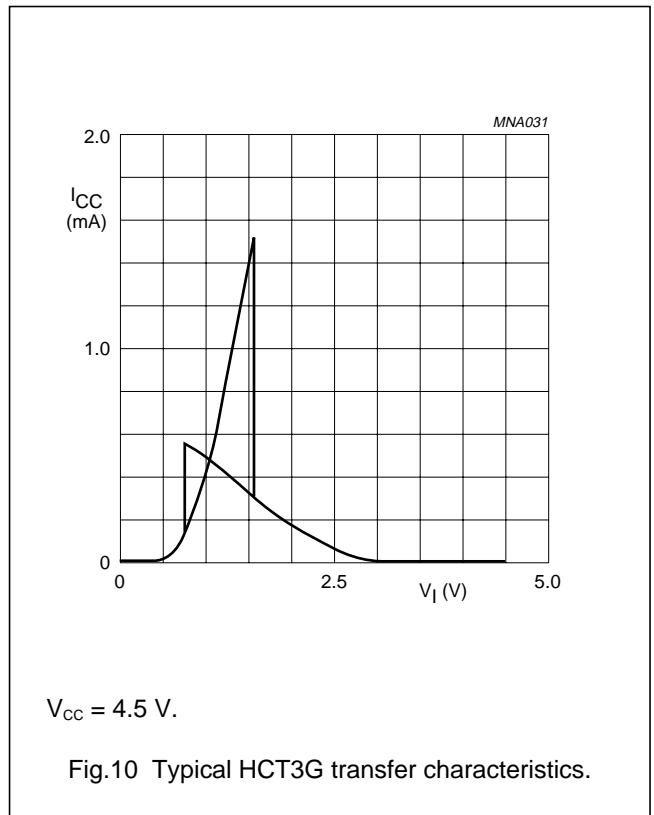
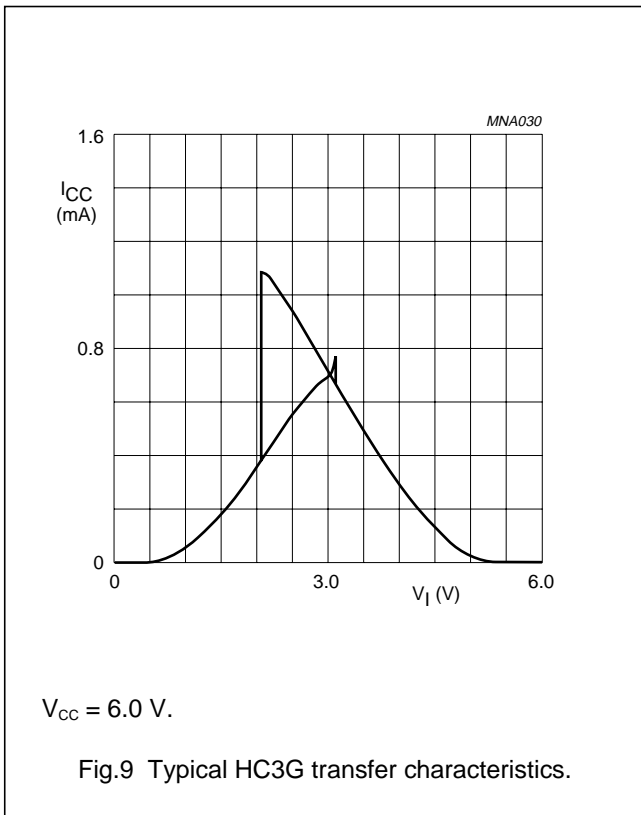
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TRANSFER CHARACTERISTIC WAVEFORMS



Inverting Schmitt-triggers

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Inverting Schmitt-triggers

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AC CHARACTERISTICS

Type 74HC3G14

GND = 0 V; $t_r = t_f \leq 6.0$ ns; $C_L = 50$ pF.

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	V _{CC} (V)				
T_{amb} = 125 °C							
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 12 and 13	2.0	–	53	125	ns
			4.5	–	16	25	ns
			6.0	–	13	21	ns
t _{THL} /t _{TLH}	output transition time	see Figs 12 and 13	2.0	–	20	75	ns
			4.5	–	7	15	ns
			6.0	–	5	13	ns
T_{amb} = –40 to +85 °C							
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 12 and 13	2.0	–	–	155	ns
			4.5	–	–	31	ns
			6.0	–	–	26	ns
t _{THL} /t _{TLH}	output transition time	see Figs 12 and 13	2.0	–	–	95	ns
			4.5	–	–	19	ns
			6.0	–	–	16	ns
T_{amb} = –40 to +125 °C							
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 12 and 13	2.0	–	–	190	ns
			4.5	–	–	38	ns
			6.0	–	–	32	ns
t _{THL} /t _{TLH}	output transition time	see Figs 12 and 13	2.0	–	–	110	ns
			4.5	–	–	22	ns
			6.0	–	–	19	ns

Inverting Schmitt-triggers

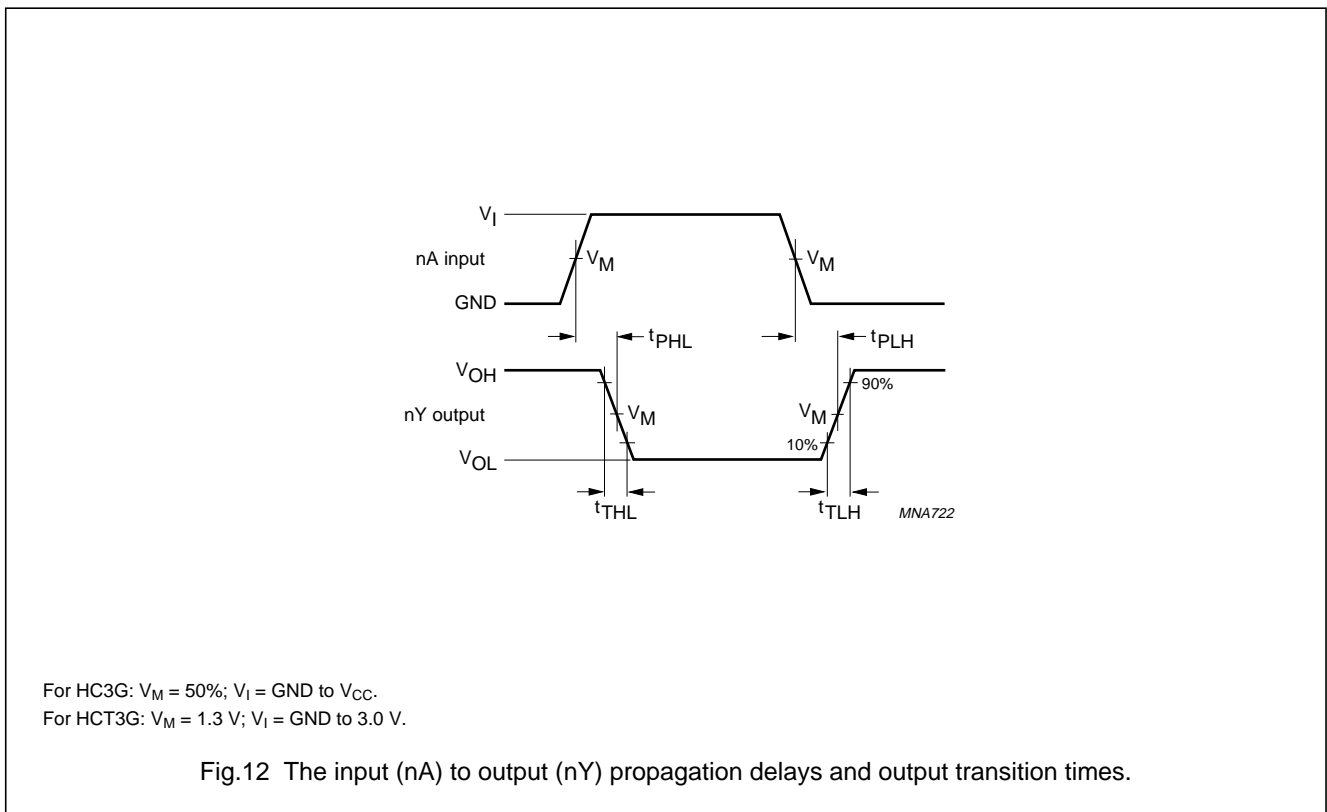
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Type 74HCT3G14

GND = 0 V; $t_r = t_f \leq 6.0$ ns; $C_L = 50$ pF.

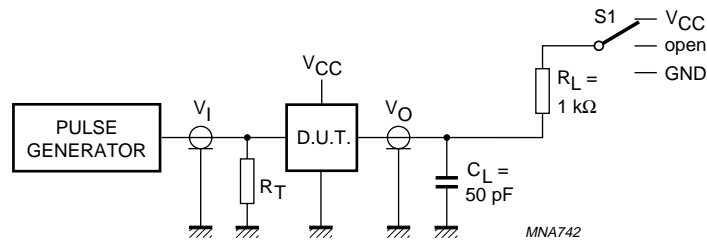
SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	V _{CC} (V)				
T_{amb} = 25 °C							
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 12 and 13	4.5	–	21	32	ns
t _{THL} /t _{TLH}	output transition time	see Figs 12 and 13	4.5	–	6	15	ns
T_{amb} = –40 to +85 °C							
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 12 and 13	4.5	–	–	40	ns
t _{THL} /t _{TLH}	output transition time	see Figs 12 and 13	4.5	–	–	19	ns
T_{amb} = –40 to +125 °C							
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 12 and 13	4.5	–	–	48	ns
t _{THL} /t _{TLH}	output transition time	see Figs 12 and 13	4.5	–	–	22	ns

AC WAVEFORMS



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TEST	S1
t_{PLH}/t_{PHL}	open
t_{PLZ}/t_{PZL}	V_{CC}
t_{PHZ}/t_{PZH}	GND

Definitions for test circuit:

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

Fig.13 Load circuitry for switching times.

Inverting Schmitt-triggers

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APPLICATION INFORMATION

Power dissipation

The slow input rise and fall times cause additional power dissipation. This can be calculated using the following formula:

$$P_{ad} = f_i \times (t_r \times I_{CC(AV)} + t_f \times I_{CC(AV)}) \times V_{CC}$$

Where:

P_{ad} = additional power dissipation (μW)

f_i = input frequency (MHz)

t_r = input rise time between 10% and 90% (ns);

t_f = input fall time between 90% and 10% (ns);

$I_{CC(AV)}$ = average additional supply current (μA).

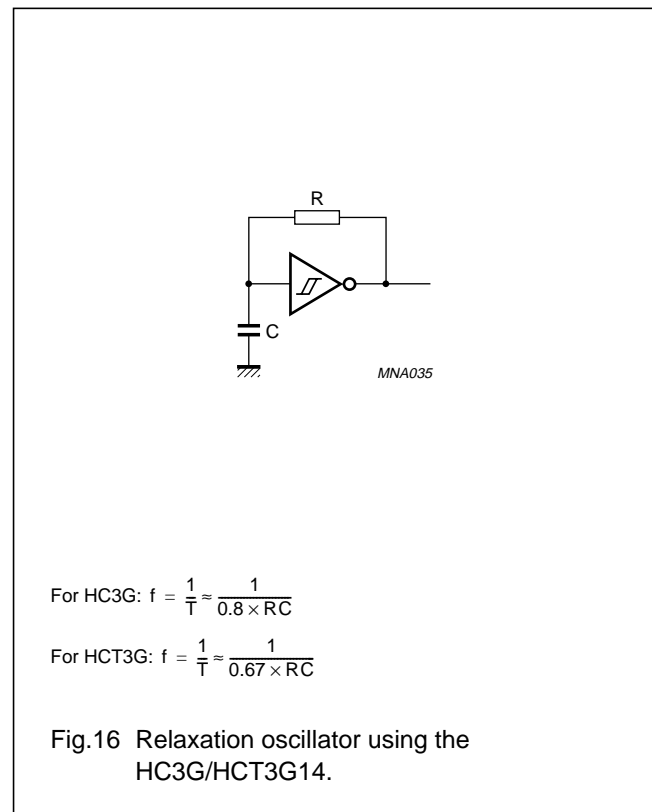
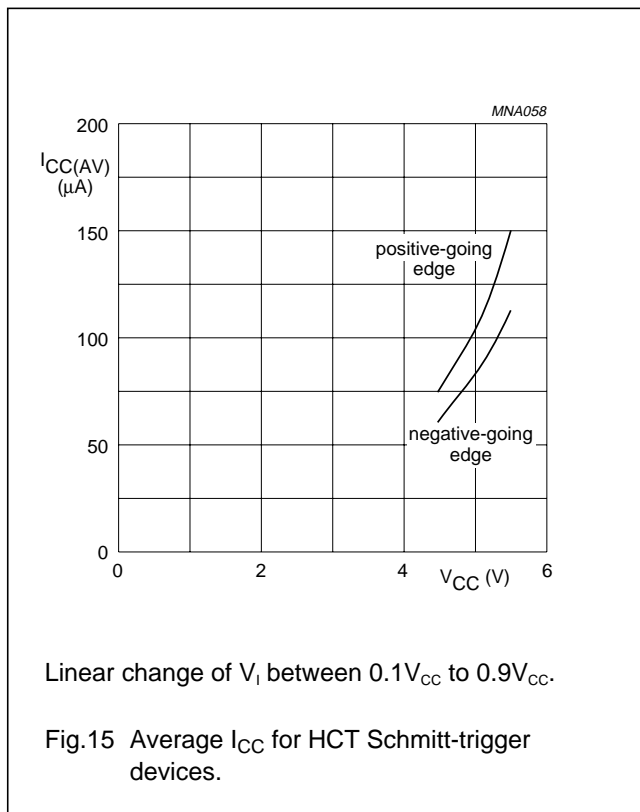
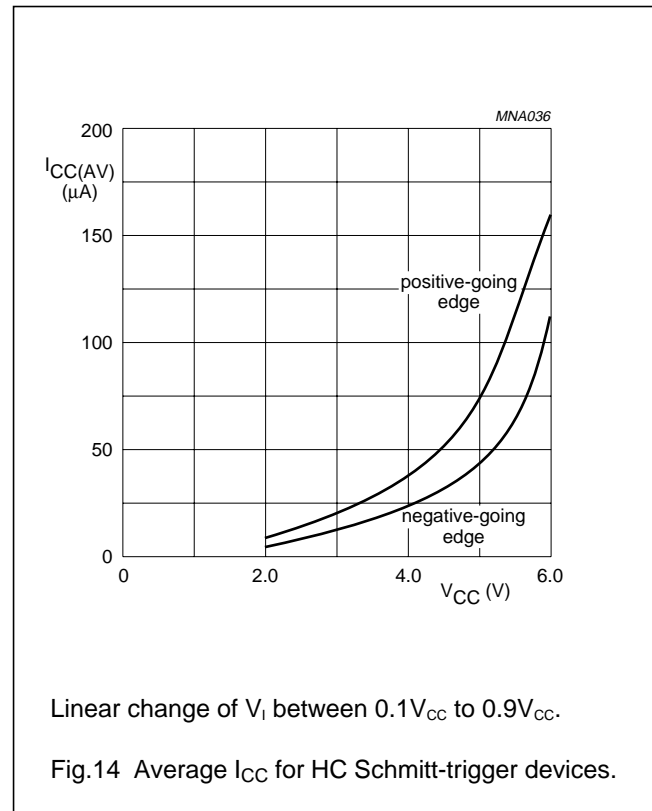
Average $I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Fig.14 and Fig.15.

Relaxation oscillator

A relaxation oscillator circuit using the HC3G14/HCT3G14 is shown in Fig.16.

Remark to the application information

All values given are typical unless otherwise specified.

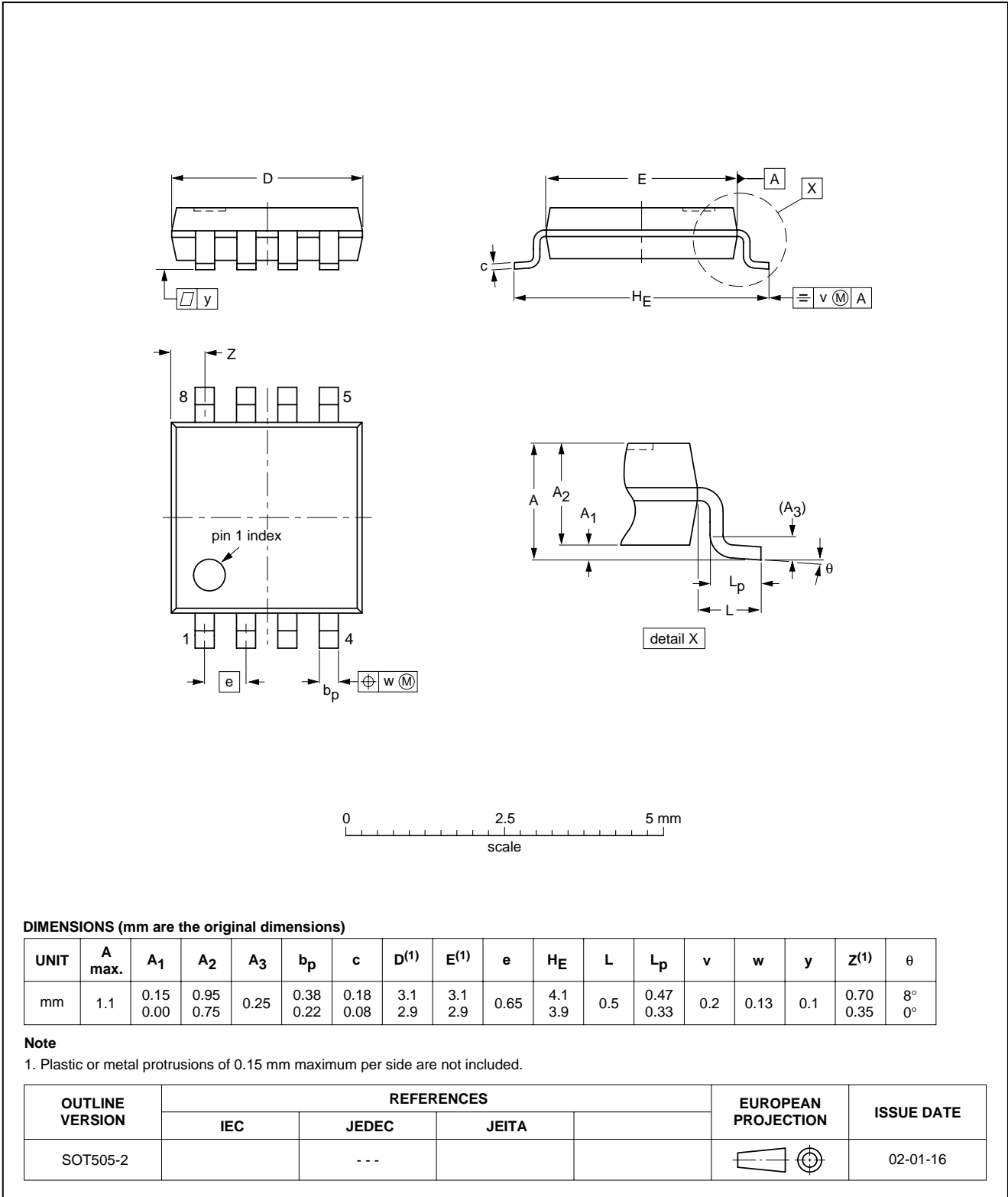


Inverting Schmitt-triggers

74HC3G14; 74HCT3G14

PACKAGE OUTLINES

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	v	w	y	Z ⁽¹⁾	θ
mm	1.1	0.15 0.00	0.95 0.75	0.25	0.38 0.22	0.18 0.08	3.1 2.9	3.1 2.9	0.65	4.1 3.9	0.5	0.47 0.33	0.2	0.13	0.1	0.70 0.35	8° 0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

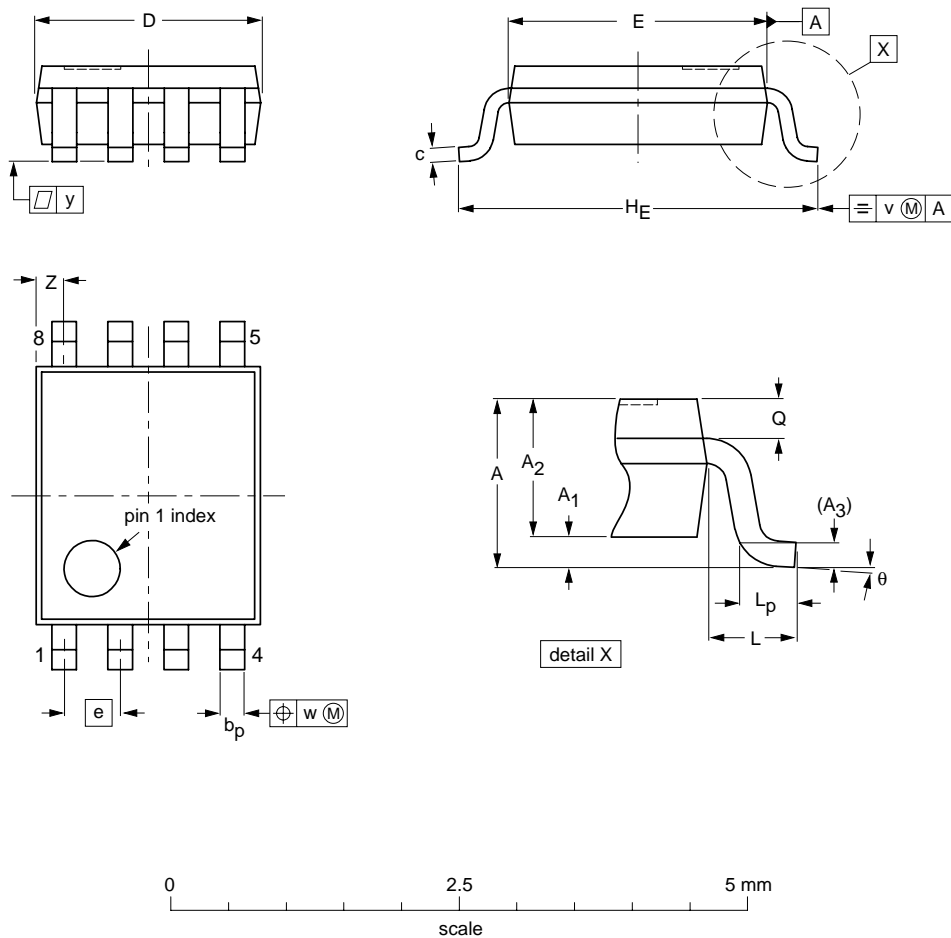
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT505-2		---				02-01-16

Inverting Schmitt-triggers

74HC3G14; 74HCT3G14

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1



DIMENSIONS (mm are the original dimensions)

UNIT	A _{max.}	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	Q	v	w	y	z ⁽¹⁾	θ
mm	1	0.15 0.00	0.85 0.60	0.12	0.27 0.17	0.23 0.08	2.1 1.9	2.4 2.2	0.5	3.2 3.0	0.4	0.40 0.15	0.21 0.19	0.2	0.13	0.1	0.4 0.1	8° 0°

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT765-1		MO-187				02-06-07

Inverting Schmitt-triggers

74HC3G14; 74HCT3G14

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Contact information

For additional information please visit <http://www.semiconductors.philips.com>. Fax: +31 40 27 24825

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